NSN 5961-01-291-4457

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-291-4457 **Inclosure Material:** Metal **Overall Length:** Between 3.573 inches and 3.788 inches **Function For Which Designed:** Rectifier **End Application:** 2350-01-277-5770 **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.660 inches and 0.720 inches **Thread Size:** 0.750 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 nonrepetitive peak reverse voltage and 300.0 repetitive peak reverse voltage and 300.0 reverse voltage, average **Current Rating Per Characteristic:** 40.00 milliamperes forward current, average major **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: